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January 2005

FAIRCHILD SEMICONDUCTOR

FDN336P

Single P-Channel 2.5V Specified PowerTrench[®] MOSFET

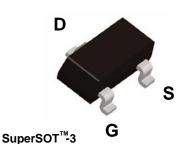
General Description

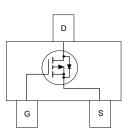
This P-Channel 2.5V specified MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

These devices are well suited for portable electronics applications: load switching and power management, battery charging circuits and DC/DC conversion.

Features

- -1.3 A, -20 V. $R_{DS(ON)} = 0.20 \ \Omega \ @ V_{GS} = -4.5 \ V$ $R_{DS(ON)} = 0.27 \ \Omega \ @ V_{GS} = -2.5 \ V$
- Low gate charge (3.6 nC typical)
- High performance trench technology for extremely low $R_{\text{DS(ON)}}$
- SuperSOTTM -3 provides low R_{DS(ON)} and 30% higher power handling capability than SOT23 in the same footprint





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-Source Voltage		-20	V	
V _{GSS}	Gate-Source Voltage		±8	V	
I _D	Drain Current – Continuous	(Note 1a)	-1.3	A	
	– Pulsed		-10		
P _D	Maximum Power Dissipation	(Note 1a)	0.5	W	
		(Note 1b)	0.46		
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C	

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	250	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	75	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
336	FDN336P	7"	8mm	3000 units
				•

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Symbol	Parameter	Conditions		Тур	Max	Units
OFF CHAR	ACTERISTICS	· · ·	•		•	
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = -250 \mu A$	-20			V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temp. Coefficient	I_{D} = -250 μ A, Referenced to 25 °C		-16		mV /°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 V, V_{GS} = 0 V$			-1	μA
		$T_{J} = 55^{\circ}C$			-10	μA
	Gate - Body Leakage, Forward	$V_{GS} = 8 V, V_{DS} = 0 V$			100	nA
GSSR	Gate - Body Leakage, Reverse	$V_{GS} = -8 V, V_{DS} = 0 V$			-100	nA
ON CHARA	CTERISTICS (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{\rm DS} = V_{\rm GS}, \ I_{\rm D} = -250 \ \mu {\rm A}$	-0.4	-0.9	-1.5	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold Voltage Temp. Coefficient	I_{D} = -250 μ A, Referenced to 25 °C		3		mV /°C
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = -4.5 \text{ V}, I_{D} = -1.3 \text{ A}$		0.122	0.2	Ω
()		T _J =125°C		0.18	0.32	
		V _{GS} = -2.5 V, I _D = -1.1 A		0.19	0.27	
I _{D(ON)}	On-State Drain Current	$V_{GS} = -4.5 \text{ V}, V_{DS} = -5 \text{ V}$	-5			Α
9 _{FS}	Forward Transconductance	$V_{DS} = -4.5 \text{ V}, I_{D} = -2 \text{ A}$		4		S
DYNAMIC C	HARACTERISTICS					
C _{iss}	Input Capacitance	$V_{DS} = -10 V, V_{GS} = 0 V,$		330		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		80		pF
C _{rss}	Reverse Transfer Capacitance			35		pF
SWITCHING	CHARACTERISTICS (Note 2)					
t _{D(on)}	Turn - On Delay Time	$V_{_{DD}} = -5 V, I_{_{D}} = -0.5 A,$		7	15	ns
t,	Turn - On Rise Time	V_{GS} = -4.5 V, R_{GEN} = 6 Ω		12	22	ns
t _{D(off)}	Turn - Off Delay Time			16	26	ns
t _r	Turn - Off Fall Time			5	12	ns
Q _g	Total Gate Charge	$V_{\rm DS} = -10 \text{ V}, \ \text{I}_{\rm D} = -2 \text{ A},$		3.6	5	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		0.8		nC
Q _{gd}	Gate-Drain Charge			0.7		nC
DRAIN-SOU	RCE DIODE CHARACTERISTICS AND MA	XIMUM RATINGS				
I _s	Maximum Continuous Drain-Source Diode Fo	orward Current			-0.42	Α
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_{S} = -0.42 A$ (Note)		-0.7	-1.2	V

Note:

1. R_{ext} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{exc} is guaranteed by design while $\mathsf{R}_{_{\theta CA}}$ is determined by the user's board design.



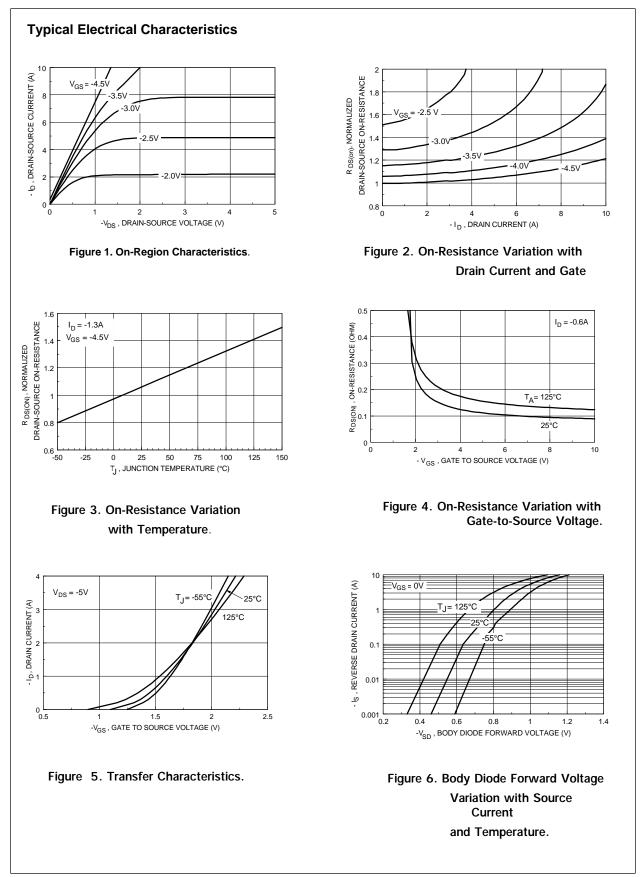
a. 250°C/W when mounted on a 0.02 in² pad of 2oz Cu.



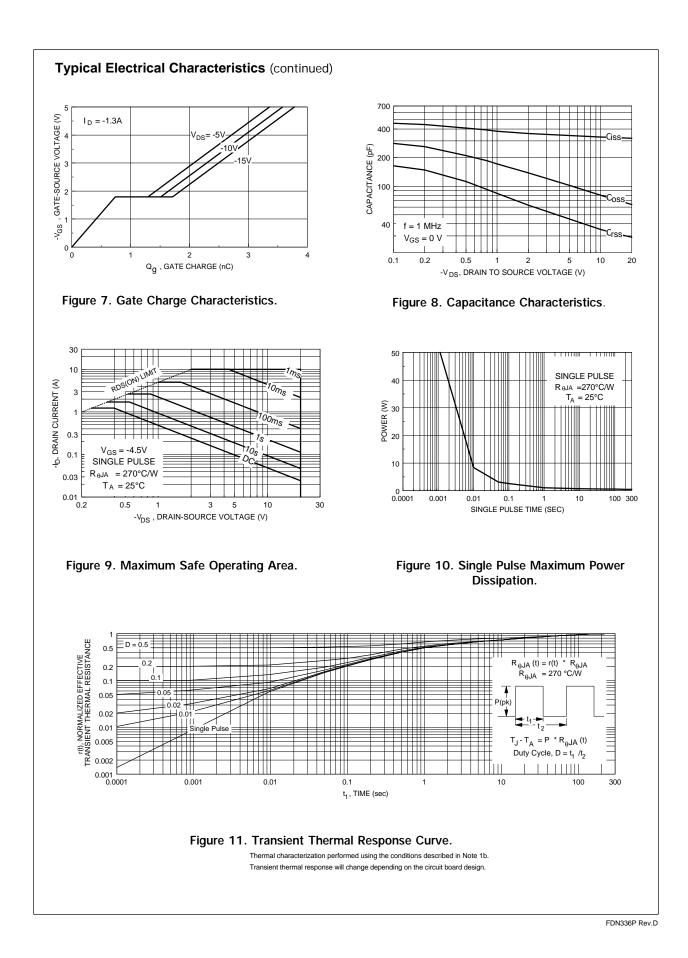
b. 270°C/W when mounted on a 0.001 in² pad of 2oz Cu.

Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%.



FDN336P Rev.D



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	CROSSVOLT™	GlobalOptoisolator™	MicroFET™	PowerTrench [®]	SuperSOT™-6
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	EnSigna™	<i>i-Lo</i> ™	MSXPro™	Quiet Series™	TINYOPTO™
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